VS-8ETL06SHM3



Vishay Semiconductors

Ultralow V_F Hyperfast Rectifier for Discontinuous Mode PFC, 8 A, FRED Pt[®]



PRIMARY CHARACTERISTICS								
I _{F(AV)}	8 A							
V _R	600 V							
V _F at I _F	0.81 V							
t _{rr} typ.	60 ns							
T _J max.	175 °C							
Package	D ² PAK (TO-263AB)							
Circuit configuration	Single							

FEATURES

- Benchmark ultralow forward voltage drop
- · Hyperfast recovery time
- Low leakage current
- 175 °C operating junction temperature
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Meets JESD 201 class 1 whisker test
- AEC-Q101 gualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

State of the art, ultralow V_F, soft-switching hyperfast rectifiers optimized for discontinuous (critical) mode (DCM) power factor correction (PFC).

The minimized conduction loss, optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

The device is also intended for use as a freewheeling diode in power supplies and other power switching applications.

APPLICATIONS

AC/DC SMPS 70 W to 400 W

e.g. laptop and printer AC adaptors, desktop PC, TV and monitor, games units and DVD AC/DC power supplies.

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS						
Peak repetitive reverse voltage	V _{RRM}		600	V						
Average rectified forward current	I _{F(AV)}	T _C = 160 °C	8							
Non-repetitive peak surge current	I _{FSM}	$T_J = 25 \ ^{\circ}C$	175	А						
Peak repetitive forward current	I _{FM}		16							
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C						

ELECTRICAL SPECIFICATIONS ($T_J = 25$ °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-	N				
Forward voltage	V _F	I _F = 8 A	-	0.96	1.05	V				
		I _F = 8 A, T _J = 150 °C	-	0.81	0.86					
Povereo lookago ourrent	1	$V_{R} = V_{R}$ rated	-	0.05	5					
Reverse leakage current	IR	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	20	100	μA				
Junction capacitance	CT	V _R = 600 V	-	17	-	pF				
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8.0	-	nH				

RoHS COMPLIANT HALOGEN FREE

Revision: 12-Jun-2023 Document Number: 96529 1 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000



www.vishay.com

Vishay Semiconductors

DYNAMIC RECOVERY CHARACTERISTICS ($T_C = 25 \text{ °C}$ unless otherwise specified)										
PARAMETER	SYMBOL	TEST C	ONDITIONS	MIN.	TYP.	MAX.	UNITS			
Reverse recovery time		$I_F = 1 \text{ A}, dI_F/dt$	= 100 A/ μ s, V _R = 30 V	-	60	100				
	+	$I_F = 8 A, dI_F/dt$	= 100 A/ μ s, V _R = 30 V	-	150	250	ns			
	t _{rr}	T _J = 25 °C		-	170	-	115			
		T _J = 125 °C		-	250	-				
Peak recovery current		T _J = 25 °C	$I_F = 8 A$	-	15	-	А			
reak recovery current	I _{RRM}	T _J = 125 °C	dl _F /dt = 200 A/µs V _B = 390 V	-	20	-	~			
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	1.3	-				
Theverse recovery charge	۷rr	T _J = 125 °C		-	2.6	-	μC			

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C				
Thermal resistance, junction to case per leg	R _{thJC}		-	1.4	2					
Thermal resistance, junction to ambient per leg	R _{thJA}	Typical socket mount	-	-	70	°C/W				
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	- 0.5 -			0/10				
Weight			-	2.0	-	g				
Weight			-	0.07	-	oz.				
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)				
Marking device		Case style D ² PAK (TO-263AB)	8ETL06SH							

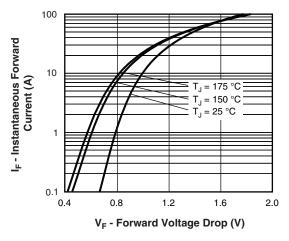


Fig. 1 - Typical Forward Voltage Drop Characteristics

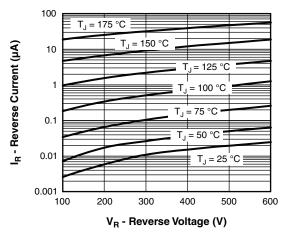


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

VS-8ETL06SHM3

Vishay Semiconductors



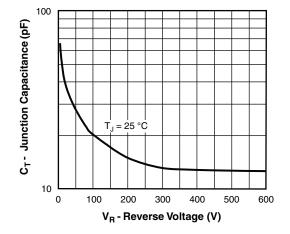


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

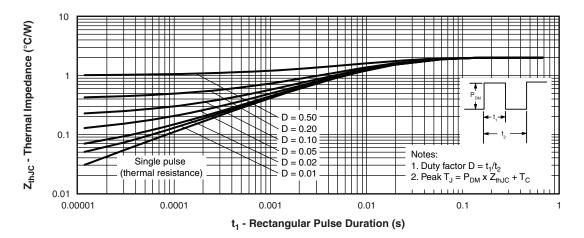
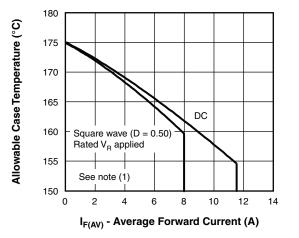
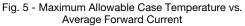


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics





Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

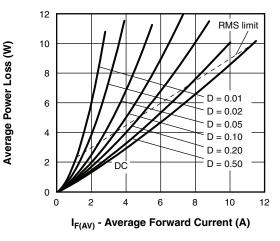


Fig. 6 - Forward Power Loss Characteristics

Revision: 12-Jun-2023

3

Document Number: 96529

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



Vishay Semiconductors



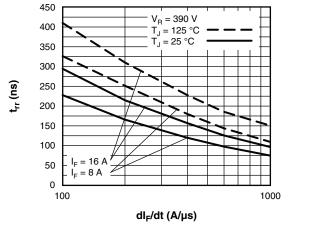


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

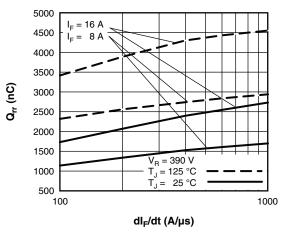


Fig. 8 - Typical Stored Charge vs. dl_F/dt

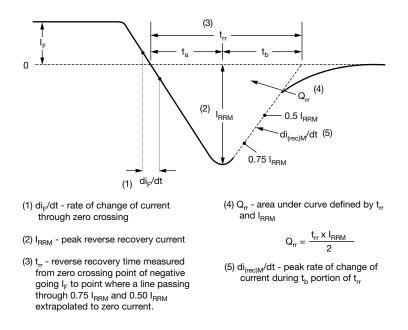


Fig. 9 - Reverse Recovery Waveform and Definitions



VISHAY, www.vishay.com

ORDERING INFORMATION TABLE

Device code	VS-	8	Е	т	L	06	S	TRL	н	М3	
		(2)	(3)	(4)	(5)	(6)	(7)	(8)	(9)	(10)	
		Ŭ	<u> </u>	Ŭ	Ŭ		0	0	0	U	
	<u> </u>	 Vishay Semiconductors product 									
	2 -	- Current rating (8 A)									
	3 -	E =	E = single diode								
	4 -	T =	TO-220	, D ² PAk	(
	5 -	L=	ultralow	V _F hype	erfast re	covery					
	6 -	Volt	age rati	ng (06 =	= 600 V)						
	7 -	• S	= D ² PA	K							
	8 -	• N	one = tu	be (50 r	vieces)						
			 None = tube (50 pieces) TRL = tape and reel (left oriented, for D²PAK package) 								
			• TRR = tape and reel (right oriented, for D ² PAK package)								
	9 -	н=	lead (P	d)-free							
	10 -	M3	= halog	en-free,	RoHS-0	complia	nt, and	terminat	tions lea	ad (Pb)-f	

ORDERING INFORMATION										
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION								
VS-8ETL06SHM3	50	Antistatic plastic tube								
VS-8ETL06STRRHM3	800	13" diameter reel								
VS-8ETL06STRLHM3	800	13" diameter reel								

LINKS TO RELATED DOCUMENTS								
Dimensions	www.vishay.com/doc?95046							
Part marking information	www.vishay.com/doc?95444							
Packaging information	www.vishay.com/doc?95032							
SPICE model	www.vishay.com/doc?96055							

Outline Dimensions



D²PAK

DIMENSIONS in millimeters and inches

www.vishay.com

SHA



SYMBOL	MILLIMETERS		INC	INCHES		NOTES		MILLIM	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

Revision: 08-Jul-15

1



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.